NPN 1.0A 50V Middle Power Transistor

Parameter	Value
V_{CEO}	50V
I _C	1.0A

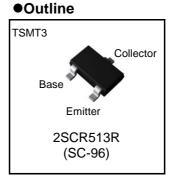
● Features

- 1) Suitable for Middle Power Driver
- 2) Complementary PNP Types: 2SAR513R
- 3) Low $V_{CE(sat)}$

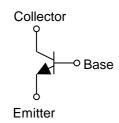
 $V_{CE(sat)}$ =0.35V(Max.)

 $(I_C/I_B=500mA/25mA)$

4) Lead Free/RoHS Compliant.



•Inner circuit



Applications

Motor driver , LED driver Power supply

Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SCR513R	TSMT3	2928	TL	180	8	3,000	NC

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	50	V
Collector-emitter voltage		V_{CEO}	50	V
Emitter-base voltage		V_{EBO}	6	V
Collector ourrent	DC	I _C	1.0	А
Collector current	Pulsed	I _{CP} *1	2.0	Α
Power dissipation		P _D *2	0.5	W
		P _D *3	1	W
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	-55 to +150	°C

^{*1} Pw=10ms, single pulse

^{*2} Each terminal mounted on a reference land

^{*3} Mounted on a ceramic board (40×40×0.7mm)

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C = 1mA	50	-	-	V
Collector-base breakdown voltage	BV _{CBO}	I _C = 100μA	50	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = 100μA	6	ı	-	V
Collector cut-off current	I _{CBO}	V _{CB} = 50V	ı	ı	1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 4V	1	-	1	μΑ
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 500 \text{mA}, I_B = 25 \text{mA}$	-	0.13	0.35	V
DC current gain	h _{FE}	$V_{CE} = 2V$, $I_C = 50$ mA	180	-	450	-
Transition frequency	f _T *1	$V_{CE} = 10V, I_{E} = -200 \text{mA}$ f=100MH _Z	-	360	-	MHz
Output capacitance	C_{ob}	$V_{CB} = 10V$, $I_E = 0A$, $f = 1MHz$	-	7	-	pF
Turn-on time	t _{on} *2	I _C =0.5A	-	40	-	ns
Storage time	t _{stg} *2	I _{B1} =50mA I _{B2} = -50mA	-	410	-	ns
Fall time	t _f *2	V _{cc} ≃10V	-	75	-	ns

^{*1} Pulsed

●Switching time test circuit V_{IN} Pw ≈ 50μs DUTY CYCLE ≤ 1% BASE CURENT WAVEFORM COLLECTOR CURRENT WAVEFORM V_{ID} V_{ID} I_{ID} V_{ID} I_{ID} V_{ID} I_{ID} I_{ID}

^{*2} See switching time test circuit

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

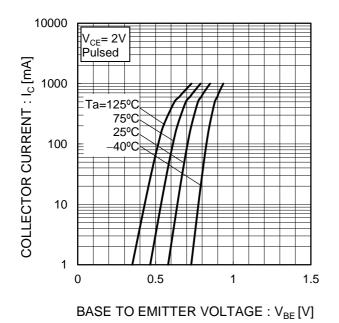
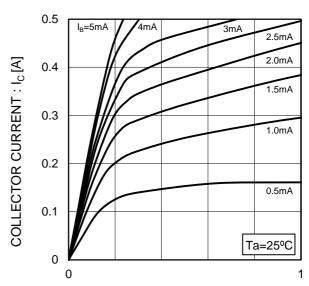


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V_{CE}[V]

Fig.3 DC Current Gain vs. Collector Current(I)

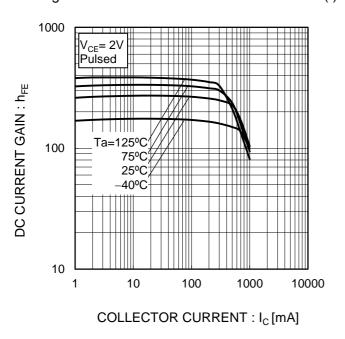
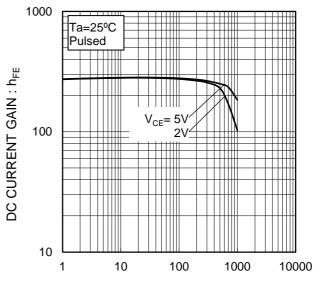
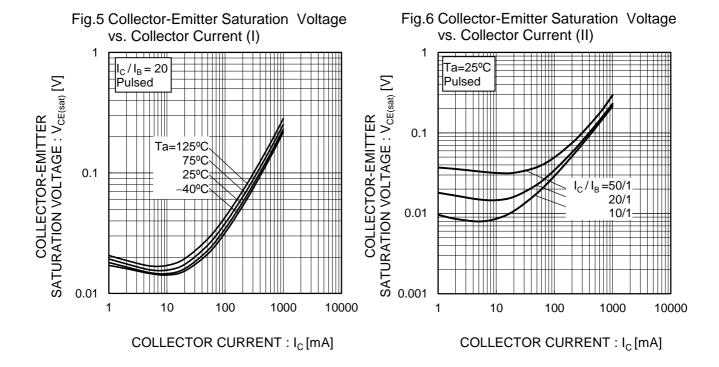


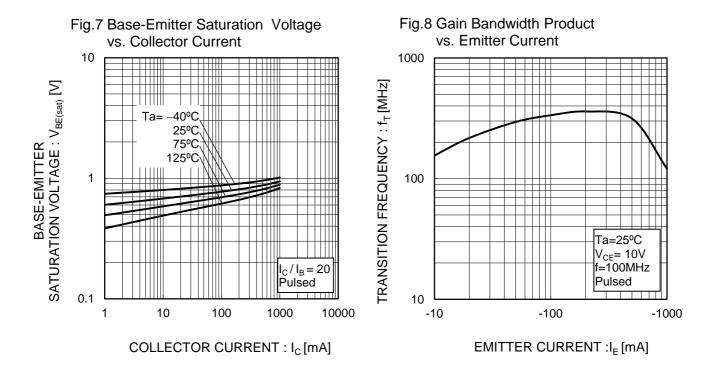
Fig.4 DC current gain vs. output current (II)



COLLECTOR CURRENT : I_C [mA]

●Electrical characteristic curves(Ta = 25°C)





●Electrical characteristic curves(Ta = 25°C)

Fig.9 Emitter input capacitance vs.

Emitter-Base Voltage
Collector output capacitance vs.
Collector-Base Voltage

1000

Ta=25°C

f=1MHz

lc=0A

Ta=25°C

f=1MHz

lc=0A

Ta=25°C

f=1MHz

lc=0A

Collector output capacitance vs.
Collector-Base Voltage

Collector-Base Voltage

Collector-Base Voltage

Collector-Base Voltage

Ta=25°C

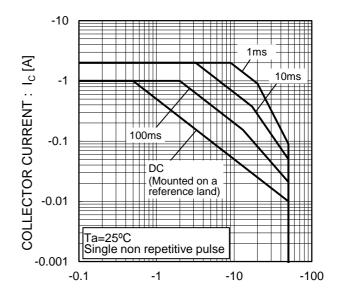
f=1MHz

lc=0A

Collector-Base Voltage

Collector

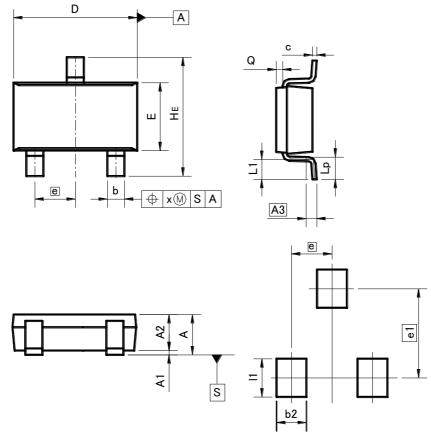
Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE: V_{CE}[V]

●Dimensions (Unit : mm)

TSMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	ı	1.00	_	0.039	
A1	0.00	0.10	0.000	0.004	
A2	0.75	0.95	0.030	0.037	
A3	0.5	25	0.0	10	
b	0.35	0.50	0.014	0.020	
С	0.10	0.26	0.004	0.010	
D	2.80	3.00	0.110	0.118	
Е	1.50	1.80	0.059	0.071	
е	0.95		0.037		
HE	2.60	3.00	0.102	0.118	
L1	0.30	0.60	0.012	0.024	
Lp	0.40	0.70	0.016	0.028	
Q	0.05	0.25	0.002	0.010	
Х	_	0.20	_	0.008	

DIM	MILIMETERS		INCHES		
MIN		MAX	MIN	MAX	
b2		0.70	_	0.028	
e1	2.10		0.0	83	
l1	_	0.90	ı	0.035	

Dimension in mm / inches

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